

isc N-Channel MOSFET Transistor

2SK684

DESCRIPTION

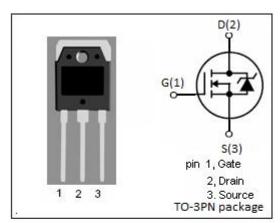
- Drain Current –I_D=7A@ T_C=25°C
- · Drain Source Voltage-
 - : V_{DSS}=800V(Min)
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

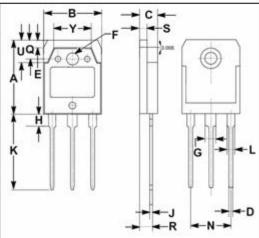


- low on-resistance
- · High speed switching
- · Low drive current
- · No secondary breakdown
- Suitable for switchingregulator, DC-DC convertor

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	800	V
V _{GS}	Gate-Source Voltage	±20	V
I _D	Drain Current-continuous@ TC=25℃	7	Α
P _{tot}	Total Dissipation@TC=25℃	100	W
T _j	Max. Operating Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$





	mm		
DIM	MIN	MAX	
Α	19.60	20.30	
В	15.50	15.70	
C	4.70	4.90	
D	0.90	1.10	
E	1.90	2.10	
F	3.40	3.60	
G	2.90	3.20	
H	3.20	3.40	
J	0.595	0.605	
K	19.80	20.70	
L	1.90	2.20	
N	10.89	10.91	
Q	4.90	5.10	
R	3.35	3.45	
S	1.995	2.100	
U	5.90	6.20	
Y	9.90	10.10	



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• ELECTRICAL CHARACTERISTICS (T_C=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0; I _D = 10mA	800			V
$V_{GS(TH)}$	Gate Threshold Voltage	V _{DS} = 10V; I _D = 1mA	2.0		4.0	V
R _{DS(ON)}	Drain-Source On-stage Resistance	V _{GS} = 10V; I _D =4A		1.0	1.5	Ω
V_{SD}	Diode Forward Voltage	I _F = 7A; V _{GS} =0		1.0		V
I _{GSS}	Gate Source Leakage Current	V _{GS} = ±16V; V _{DS} = 0			±10	uA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =640V; V _{GS} = 0			250	uA



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